MOTOROLA

SN54/74LS242
SN54/74LS243

QUAD BUS TRANSCEIVER

The SN54/74LS242 and SN54/74LS243 are Quad Bus Transmitters/Receivers designed for 4-line asynchronous 2-way data communications between data buses.

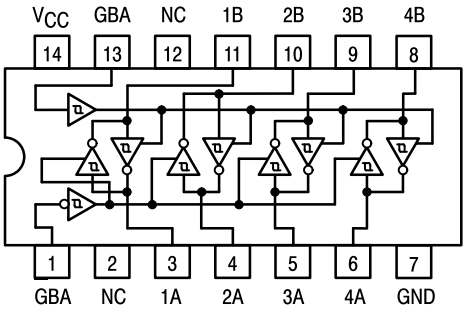
- Hysteresis at Inputs to Improve Noise Immunity
- 2-Way Asynchronous Data Bus Communication
- Input Clamp Diodes Limit High-Speed Termination Effects

QUAD BUS TRANSCEIVER

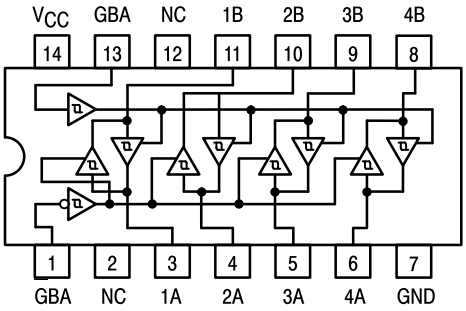
LOW POWER SCHOTTKY

LOGIC AND CONNECTION DIAGRAMS DIP (TOP VIEW)

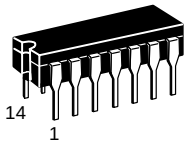
SN54/74LS242



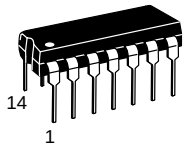
SN54/74LS243



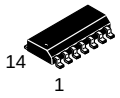
NOTE:
The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.



J SUFFIX
CERAMIC
CASE 632-08



N SUFFIX
PLASTIC
CASE 646-06



D SUFFIX
SOIC
CASE 751A-02

ORDERING INFORMATION

SN54LSXXXJ	Ceramic
SN74LSXXXN	Plastic
SN74LSXXXDW	SOIC

TRUTH TABLES

SN54/74LS242

INPUTS		OUTPUT	INPUTS		OUTPUT
$\overline{GAB}$	D		$\overline{GAB}$	D	
L	L	H	L	X	(Z)
L	H	L	H	L	H
H	X	(Z)	H	H	L

SN54/74LS243

INPUTS		OUTPUT	INPUTS		OUTPUT
$\overline{GAB}$	D		$\overline{GAB}$	D	
L	L	L	L	X	(Z)
L	H	H	H	L	H
H	X	(Z)	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance

GUARANTEED OPERATING RANGES

Symbol	Parameter		Min	Typ	Max	Unit
V_{CC}	Supply Voltage	54 74	4.5 4.75	5.0 5.0	5.5 5.25	V
T_A	Operating Ambient Temperature Range	54 74	−55 0	25 25	125 70	°C
I_{OH}	Output Current — High	54, 74			−3.0	mA
		54 74			−12 −15	mA
I_{OL}	Output Current — Low	54 74			12 24	mA

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter		Limits Min	Limits Typ	Limits Max	Unit	Test Conditions	
V_{IH}	Input HIGH Voltage		2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V_{IL}	Input LOW Voltage	54			0.7	V	Guaranteed Input LOW Voltage for All Inputs	
		74			0.8			
$V_{T+}-V_{T-}$	Hysteresis		0.2	0.4		V	V_{CC} = MIN	
V_{IK}	Input Clamp Diode Voltage			−0.65	−1.5	V	V_{CC} = MIN, I_{IN} = −18 mA	
V_{OH}	Output HIGH Voltage	54, 74	2.4	3.4		V	V_{CC} = MIN, I_{OH} = −3.0 mA	
		54, 74	2.0			V	V_{CC} = MIN, I_{OH} = MAX	
V_{OL}	Output LOW Voltage	54, 74		0.25	0.4	V	I_{OL} = 12 mA	V_{CC} = V_{CC} MIN, V_{IN} = V_{IL} or V_{IH} per Truth Table
		74		0.35	0.5	V	I_{OL} = 24 mA	
I_{OZH}	Output Off Current HIGH				40	µA	V_{CC} = MAX, V_{OUT} = 2.7 V	
I_{OZL}	Output Off Current LOW				−200	µA	V_{CC} = MAX, V_{OUT} = 0.4 V	
I_{IH}	Input HIGH Current	D, $\overline{E_1}$, E_2			20	µA	V_{CC} = MAX, V_{IN} = 2.7 V	
		$\overline{E_1}$, E_2			0.1	mA	V_{CC} = MAX, V_{IN} = 7.0 V	
		D Input			0.1	mA	V_{CC} = MAX, V_{IN} = 5.5 V	
I_{IL}	Input LOW Current				−0.2	mA	V_{CC} = MAX, V_{IN} = 0.4 V	
I_{OS}	Output Short Circuit Current (Note 1)		−40		−225	mA	V_{CC} = MAX	
I_{CC}	Power Supply Current Total, Output HIGH				38	mA	V_{CC} = MAX	
	Total, Output LOW				50			
	Total at HIGH Z	LS242			50			
		LS243			54			

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

Symbol	Parameter	Limits						Unit	Test Conditions
		LS242			LS243				
		Min	Typ	Max	Min	Typ	Max		
t_{PLH} t_{PHL}	Propagation Delay, Data to Output		9.0 12	14 18		12 12	18 18	ns	C_L = 45 pF, R_L = 667 Ω
t_{PZH}	Output Enable Time to HIGH Level		15	23		15	23	ns	
t_{PZL}	Output Enable Time to LOW Level		20	30		20	30	ns	
t_{PLZ}	Output Disable Time from LOW Level		15	25		15	25	ns	C_L = 5.0 pF, R_L = 667 Ω
t_{PHZ}	Output Disable Time from HIGH Level		10	18		10	18	ns	

AC WAVEFORMS

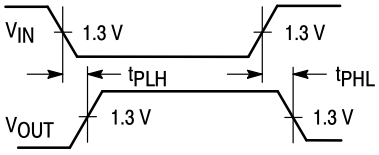


Figure 1

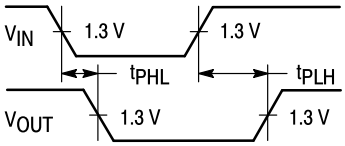


Figure 2

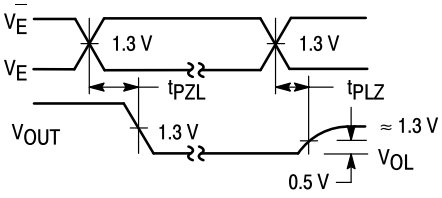


Figure 3

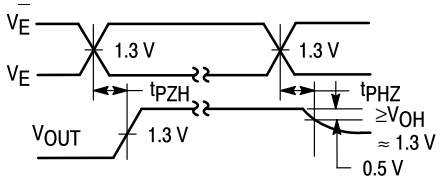
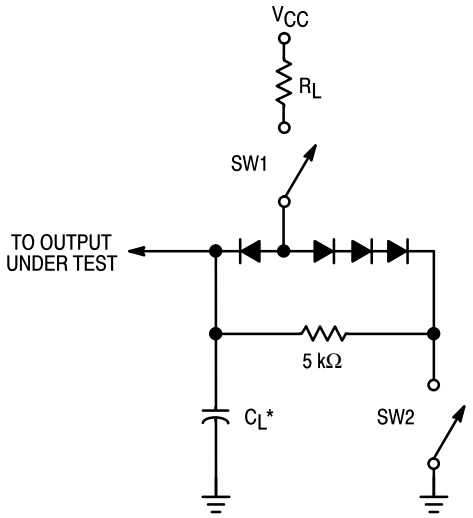


Figure 4

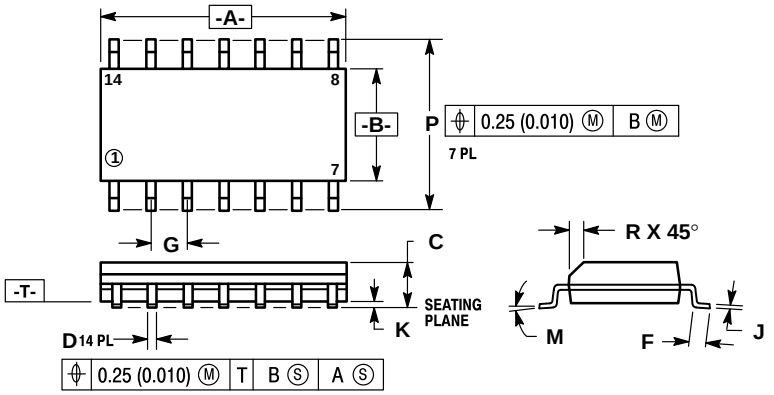


SWITCH POSITIONS

SYMBOL	SW1	SW2
t_{PZH}	Open	Closed
t_{PZL}	Closed	Open
t_{PLZ}	Closed	Closed
t_{PHZ}	Closed	Closed

Figure 5

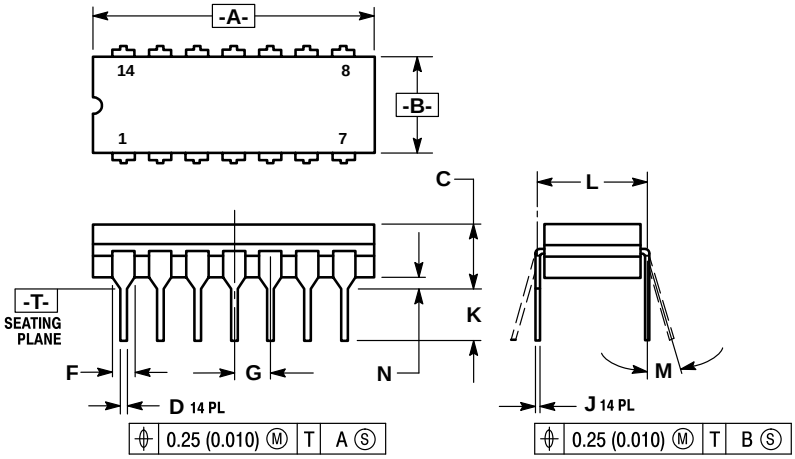
Case 751A-02 D Suffix
14-Pin Plastic
SO-14



NOTES:
1. DIMENSIONS "A" AND "B" ARE DATUMS AND "T" IS A DATUM SURFACE.
2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
3. CONTROLLING DIMENSION: MILLIMETER.
4. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
5. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
6. 751A-01 IS OBSOLETE, NEW STANDARD 751A-02.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

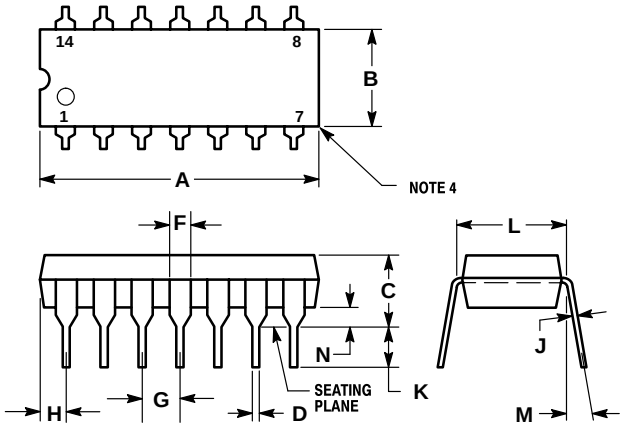
Case 632-08 J Suffix
14-Pin Ceramic Dual In-Line



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIM F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.
5. 632-01 THRU -07 OBSOLETE, NEW STANDARD 632-08.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	19.05	19.94	0.750	0.785
B	6.23	7.11	0.245	0.280
C	3.94	5.08	0.155	0.200
D	0.39	0.50	0.015	0.020
F	1.40	1.65	0.055	0.065
G	2.54 BSC		0.100 BSC	
J	0.21	0.38	0.008	0.015
K	3.18	4.31	0.125	0.170
L	7.62 BSC		0.300 BSC	
M	0°	15°	0°	15°
N	0.51	1.01	0.020	0.040

Case 646-06 N Suffix
14-Pin Plastic



NOTES:
1. LEADS WITHIN 0.13 mm (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
2. DIMENSION "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
3. DIMENSION "B" DOES NOT INCLUDE MOLD FLASH.
4. ROUNDED CORNERS OPTIONAL.
5. 646-05 OBSOLETE, NEW STANDARD 646-06.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	18.16	19.56	0.715	0.770
B	6.10	6.60	0.240	0.260
C	3.69	4.69	0.145	0.185
D	0.38	0.53	0.015	0.021
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	1.32	2.41	0.052	0.095
J	0.20	0.38	0.008	0.015
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	0°	10°	0°	10°
N	0.39	1.01	0.015	0.039

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